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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/735,989 12/15/2003		Somenath Mitra	436/12	4147	
27538	7590 03/28/2005		EXAMINER		
KAPLAN & GILMAN , L.L.P. 900 ROUTE 9 NORTH			FASTOVSKY, LEONID M		
	GE, NJ 07095		ART UNIT	PAPER NUMBER	
			3742		

DATE MAILED: 03/28/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applicat	ion No.	Applicant(s)	
			989	MITRA ET AL.	\mathcal{O}
	Office Action Summary	Examine	er	Art Unit	
		Leonid M	l Fastovsky	3742	
	The MAILING DATE of this communi	cation appears on th	ne cover sheet with the o	correspondence addr	ess
THE I - External after - If the - If NO - Failu Any	ORTENED STATUTORY PERIOD FO MAILING DATE OF THIS COMMUNION of time may be available under the provisions of time may be available under the provisions of SIX (6) MONTHS from the mailing date of this common period for reply specified above is less than thirty (30 period for reply is specified above, the maximum stare to reply within the set or extended period for reply reply received by the Office later than three months all ed patent term adjustment. See 37 CFR 1.704(b).	CATION. of 37 CFR 1.136(a). In no e unication. of days, a reply within the statutory period will apply and will, by statute, cause the ap	vent, however, may a reply be tir atutory minimum of thirty (30) day will expire SIX (6) MONTHS from oplication to become ABANDONE	nely filed rs will be considered timely. the mailing date of this comic (35 U.S.C. § 133).	munication.
Status				•	
2a)□	Responsive to communication(s) file. This action is FINAL . Since this application is in condition to closed in accordance with the practice.	b)⊠ This action is for allowance excep	non-final. ot for formal matters, pro		nerits is
Dispositi	on of Claims				
5)□ 6)⊠ 7)□	Claim(s) 1-20 is/are pending in the a 4a) Of the above claim(s) is/ar Claim(s) is/are allowed. Claim(s) 1-20 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restrice.	e withdrawn from co			
Applicati	ion Papers				
10)⊠	The specification is objected to by the The drawing(s) filed on 15 December Applicant may not request that any object Replacement drawing sheet(s) including The oath or declaration is objected to	: <u>2003</u> is/are: a)⊠ a tion to the drawing(s) the correction is requ	be held in abeyance. Se ired if the drawing(s) is ob	e 37 CFR 1.85(a). ejected to. See 37 CFR	R 1.121(d).
Priority i	ınder 35 U.S.C. § 119	•			
a)	Acknowledgment is made of a claim of All b) Some * c) None of: 1. Certified copies of the priority of the priority of the priority of the certified copies of the priority of the certified copies of the priority of the certified copies of the certified c	documents have be documents have be of the priority docum nal Bureau (PCT Ru	en received. en received in Applicat nents have been receiv ule 17.2(a)).	ion No ed in this National S	tage
2) Notice 3) Information	et(s) te of References Cited (PTO-892) te of Draftsperson's Patent Drawing Review (Pmation Disclosure Statement(s) (PTO-1449 or tr No(s)/Mail Date		4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal I 6) Other:	ate	152)

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DETAILED ACTION

Specification

1. The abstract of the disclosure is objected to because it contains an extraneous word "comprising" (line 2). Correction is required. See MPEP § 608.01(b).

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 1-2, 5, 10-11,14-15 and 18 are rejected under 35 U.S.C. 102(e) as being anticipated by Jun et al (6,582,987).

Jun teaches a microheater and method of fabricating the microheater for microfluidic devices comprising a microchannel 202 formed on a silicon substrate 201 and a conductor- microheater 214 formed in the microchannel 202 and comprising a metal layer 215 (col. 7, lines 10-17).

As for claim 15, Jun teaches etching of the substrate 201 (col. 6, lines 60-65).

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Claim Rejections - 35 USC § 103

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 3 and 6-7 and 12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Jun in view of Ferguson (2003/0209534).

Jun discloses substantially the claimed invention, but does not disclose quartz and borosilicate glass. Ferguson discloses resistive heating systems with a substrate 202 comprising quartz and borosilicate glass (page 10, [0068]). It would have been obvious to one having ordinary skill in the art to modify Jun's invention to include the substrate comprising quartz and borosilicate glass as taught by Ferguson in order to provide a more rigid structure for the microheater.

As to claim 3 and the limitation of the conductor comprising an aluminum alloy with 99% aluminum and silicon and copper, it is deemed that the material used for conductor would be chosen by user having a desired result in mind. Therefore it would have been obvious to have made the conductor made out of 99% aluminum and silicon and copper as to obtain the result wanted by the user.

6. Claims 4 and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Jun in view of Yamazaki (6,165,876) and further in view of Ueno et al (2002/00224662). Jun discloses substantially the claimed invention, but does not disclose a substrate comprising a polished silicon wafer, and a conductor-heater comprising boron ions.

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Yamazaki discloses a method of doping a silicon film 203 with boron ion (col. 15, lines 1-18). Ueno discloses a microfluidic device having a heater 3 with a mirror- polished substrate (page 5, [0094]). It would have been obvious to one having ordinary skill in the art to modify Jun's invention to include a boron doped substrate as taught by Yamazaki and a polished substrate as taught by Ueno and a conductor comprising boron ions as taught by Yamazaki in order to assure better heating conditions for the microheater.

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- 7. Claims 16-17 are rejected under 35 U.S.C. 103(a) as being unpatentable over Jun in view of Yamazaki. Jun in view of Yamazaki discloses substantially the claimed invention, but does not teach boron ion implantation. Yamazaki teaches a method of implanting boron (col. 15, lines 1-10). It would have been obvious to one having ordinary skill in the art to modify the invention of Jun and Yamazaki to provide a method for fabricating a microheater because prior art references do teach performing a process and also structure limitations of the invention.
- 8. Claims 9, 13 and 20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Jun in view of Gaitan et al (5,464,966).

Jun discloses substantially the claimed invention, but does not discloses a glass layer disposed on the conductior-heater. Gaitan discloses a micro-hotplate device having a conductor heater 5 comprising a glass-silicone layer 13 (Fig. 5). It would have been obvious to one having ordinary skill in the art to modify Jun's invention to include a glass-silicone oxide layer as taught by Gaitan in order to provide protective insulation.

9. Claim 19 is rejected under 35 U.S.C. 103(a) as being unpatentable over Jun.

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Jun discloses substantially the claimed invention including a conductor-heater 214 comrising a metal layer 215, but does not specify the matal material. It would have been obvious to one having ordinary skill in the art to modify Jun's invention to include the conductor comprising aluminum as an obvious functional equivalent.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Leonid M Fastovsky whose telephone number is 571-272-4778. The examiner can normally be reached on M-Th. 8.00 am -6.00 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robin Evans can be reached on 571-272-4777. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Leonid M Fastovsky

Examiner Art Unit 3742

Imf

ROBIN O. EVANS
PRIMARY EXAMINER